DIODES, POWER RECTIFIER, HIGH EFFICIENCY, FAST RECOVERY

BASED ON TYPE BYV54-200

ESCC Detail Specification No. 5103/031

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DOCUMENTATION CHANGE NOTICE

(Refer to https://escies.org for ESCC DCR content)

DCR No.	CHANGE DESCRIPTION
760	Specification up issued to incorporate technical changes per DCR.

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1. GENERAL

1.1 SCOPE

This specification details the ratings, physical and electrical characteristics and test and inspection data for the component type variants and/or the range of components specified below. It supplements the requirements of, and shall be read in conjunction with, the ESCC Generic Specification listed under Applicable Documents.

1.2 APPLICABLE DOCUMENTS

The following documents form part of this specification and shall be read in conjunction with it:

(a) ESCC Generic Specification No. 5000
(b) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices

1.3 TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESCC Basic Specification No. 21300 shall apply.

1.4 THE ESCC COMPONENT NUMBER AND COMPONENT TYPE VARIANTS

1.4.1 The ESCC Component Number

The ESCC Component Number shall be constituted as follows:

Example: 510303101

- Detail Specification Reference: 5103031
- Component Type Variant Number: 01 (as required)

1.4.2 Component Type Variants

The component type variants applicable to this specification are as follows:

The lead material and finish shall be in accordance with the requirements of ESCC Basic Specification No. 23500.

Variant Number	Based on Type	Case	Description	Lead Material and Finish	Weight max g
01	BYV54-200	TO-254	Single diode	H9	10
02	BYV54-200	TO-254	Single diode	H14	10
03	BYV54-200	TO-254	Single diode	H4	10
04	BYV54-200	TO-254AA	Single diode - Low Ohmic Package	S14	10
05	BYV54-200	TO-254AA	Single diode - Low Ohmic Package	S4	10

1.5 MAXIMUM RATINGS

The maximum ratings shall not be exceeded at any time during use or storage.

Maximum ratings shall only be exceeded during testing to the extent specified in this specification and when stipulated in Test Methods and Procedures of the ESCC Generic Specification.

Characteristics	Symbols	Maximum Ratings	Unit	Remarks
Forward Surge Current	I_{FSM}	400	A	Note 1
Repetitive Peak Reverse Voltage	V_{RRM}	200	V	Note 2
Average Output Rectified Current	I_O	40	A	50% Duty Cycle Note 3
RMS Forward Current	$I_{F(rms)}$	60	A	
Operating Temperature Range (Case Temperature)	T_{op}	-55 to +150	°C	Note 4
Junction Temperature	T_j	+150	°C	
Storage Temperature Range	T_{stg}	-55 to +150	°C	Note 4
Soldering Temperature	T_{sol}	+260	°C	Note 5
Thermal Resistance, Junction to Case	$R_{th(j-c)}$	1	°C/W	Note 6

NOTES:

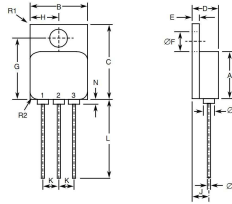
1. Sinusoidal pulse of 10ms duration.
2. Pulse, duration 5ms, f = 50Hz.
3. At T_{case} > +90°C, derate linearly to 0A at +150°C for Variants 01, 02, 03. At T_{case} > +99°C, derate linearly to 0A at +150°C for Variants 04, 05.
4. For Variants 01, 03, 05, with hot solder dip lead finish, all testing performed at T_{amb} > +125°C shall be carried out in a 100% inert atmosphere.
5. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.
6. Package mounted on an infinite heatsink.

1.6 HANDLING PRECAUTIONS

The TO-254 and TO-254AA packages contain Beryllium Oxide (BeO) and therefore must not be ground, machined, sandblasted or subjected to any mechanical operation which will produce dust. The case must not be subjected to any chemical process (e.g. etching) which will produce fumes.

1.7 PHYSICAL DIMENSIONS AND TERMINAL IDENTIFICATION

Metal Flange Mount Package (TO-254 & TO-254AA) - 3 lead



Symbols	Dimensions mm		Notes
	Min	Max	
A	13.59	13.84	
B	13.59	13.84	
C	20.07	20.32	
D	6.3	6.7	
E	1	1.35	
ØF	3.5	3.9	
G	16.89	17.4	
H	6.86 BSC		
Øl	0.89	1.14	2
J	3.81 BSC		
K	3.81 BSC		
L	12.95	14.5	
ØM	3.05 Typical		2
N	-	0.71	2
R1	-	1	3
R2	1.65 Typical		4

NOTES:

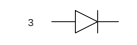
1. The terminal identification is specified by the components geometry. See Functional Diagram for the

terminal connections.
2. 3 places.
3. Radius of heatsink flange corner, 4 places.
4. Radius of body corner, 4 places.

1.8 FUNCTIONAL DIAGRAM

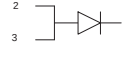
Variants 01, 02, 03

Terminal 1: Cathode
Terminal 2: Not connected
Terminal 3: Anode



Variants 04, 05

Terminal 1: Cathode
Terminal 2: Anode
Terminal 3: Anode



NOTES:
1. The case is not connected to any lead.

1.9 MATERIALS AND FINISHES
Materials and finishes shall be as follows:

a) Case
The case shall be hermetically sealed and have a metal body. The leads pass through ceramic eyelets brazed into the frame and the lid shall be welded.
b) Leads
As specified in Component Type Variants.

2. REQUIREMENTS

2.1 GENERAL
The complete requirements for procurement of the components specified herein are as stated in this specification and the ESCC Generic Specification. Permitted deviations from the Generic Specification, applicable to this specification only, are listed below.

Permitted deviations from the Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESCC requirement and do not affect the component's reliability, are listed in the appendices attached to this

specification.

2.1.1 Deviations from the Generic Specification

2.1.1.1 Deviations from Qualification and Periodic Tests - Chart F4

(a) Constant Acceleration is not applicable.

2.2 MARKING

The marking shall be in accordance with the requirements of ESCC Basic Specification No. 21700 and as follows.

The information to be marked on the component shall be:

(a) The ESCC qualified components symbol (for ESCC qualified components only).
(b) The ESCC Component Number.
(c) Traceability information.
(d) Warning sign for Beryllium Oxide.

2.3 TERMINAL STRENGTH

The test conditions for Terminal Strength, tested as specified in the ESCC Generic Specification, shall be as follows:

Test Condition: A, tension, with an applied force of 10N for a duration of 10s.

2.4 ELECTRICAL MEASUREMENTS AT ROOM, HIGH AND LOW TEMPERATURES

Electrical measurements shall be performed at room, high and low temperatures.

Consolidated notes are given after the Tables.

2.4.1 Room Temperature Electrical Measurements

The measurements shall be performed at T_{amb}=+22 ±3°C.

Characteristics	Symbols	MIL-STD-750 Test Method	Test Conditions (Note 1)	Limits		Units
				Min	Max	
Reverse Current	I_R	4016	DC Method V_R = 200V	-	50	µA
Forward Voltage 1	V_{F1}	4011	Pulse Method I_F=20A, Note 2 Variants 01, 02, 03 Variants 04, 05	-	 1.1 0.95	V
Forward Voltage 2	V_{F2}	4011	Pulse Method I_F=30A, Note 2 Variants 01, 02, 03 Variants 04, 05	-	 1.3 1.1	V

Characteristics	Symbols	MIL-STD-750 Test Method	Test Conditions (Note 1)	Limits		Units
				Min	Max	
Breakdown Voltage	$V_{(BR)}$	4021	I_R = 100µA	200	-	V
Capacitance	C	4001	V_R = 10V f = 1MHz	-	400	pF
ReverseRecovery Time	t_{rr}	4031	Test Condition A I_F=1A V_R= 30V dI_F/dt=-50A/µs	-	60	ns
Thermal Impedance, Junction to Case	$Z_{th(j-c)}$	3101	I_H = 15V to 40A t_H = 50ms I_M = 50mA t_{md} = 100µs Note 3	(Calculate ΔV_F, see Note 4)		°C/W

2.4.2 High and Low Temperatures Electrical Measurements

Characteristics	Symbols	MIL-STD-750 Test Method	Test Conditions (Notes 1, 5)	Limits		Units
				Min	Max	
Reverse Current	I_R	4016	T_{case}=+125(+0 -5)°C DC Method V_R = 200V	-	40	mA
Forward Voltage 1	V_{F1}	4011	T_{case}=+125(+0 -5)°C Pulse Method I_F=20A, Note 2 Variants 01, 02, 03 Variants 04, 05	-	 1 0.85	V
			T_{case}=-55(+5 -0)°C Pulse Method I_F=20A, Note 2 Variants 01, 02, 03 Variants 04, 05	-	 1.3 1.15	V
Forward Voltage 2	V_{F2}	4011	T_{case}=+125(+0 -5)°C Pulse Method I_F = 30A, Note 2 Variants 01, 02, 03 Variants 04, 05	-	 1.1 1	V

2.4.3 Notes to Electrical Measurement Tables

1. For Variants 04, 05 testing shall be performed with both anode terminals 2 and 3 tied together.
2. Pulsed Width ≤ 680µs, Duty Cycle ≤ 2%.
3. Performed only during Screening Tests Parameter Drift Values (Initial Measurements), go-no-go.
4. The limits for ΔV_F shall be defined by the Manufacturer on every lot in accordance with MIL-STD-750 Method 3101 and shall guarantee the $R_{th(j-c)}$ limits specified in Maximum Ratings.
5. Read and record measurements shall be performed on a sample of 5 components with 0 failures allowed. Alternatively a 100% inspection may be performed.

2.5 PARAMETER DRIFT VALUES

Unless otherwise specified, the measurements shall be performed at T_{amb}=+22 ±3°C.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements.

The drift values (Δ) shall not be exceeded for each characteristic specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits			Units
		Drift Value Δ	Absolute		
			Min	Max	
Reverse Current	I_R	±6 or (1) ±100%	-	50	µA
Forward Voltage 1 Variants 01, 02, 03 Variants 04, 05	V_{F1}	±0.07	-	 1.1 0.95	V

NOTES:

1. Whichever is the greater referred to the initial value.

2.6 INTERMEDIATE AND END-POINT ELECTRICAL MEASUREMENTS

Unless otherwise specified, the measurements shall be performed at T_{amb}=+22 ±3°C.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements. The limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits		Units
		Min	Max	
Reverse Current	I_R	-	50	µA
Forward Voltage 1 Variants 01, 02, 03 Variants 04, 05	V_{F1}	-	 1.1 0.95	V
Forward Voltage 2 Variants 01, 02, 03 Variants 04, 05	V_{F2}	-	 1.3 1.1	V

2.7 HIGH TEMPERATURE REVERSE BIAS BURN-IN CONDITIONS

Characteristics	Symbols	Limits	Units
Ambient Temperature	T_{amb}	+150 (+0 -5)	°C
Reverse Voltage	V_R	160	V

Characteristics	Symbols	Limits	Units
Ambient Temperature	T_{amb}	+150 (+0 -5)	°C
Duration	t	≥48	hours

NOTES:
1. For Variants 04, 05 testing shall be performed with both anode terminals 2 and 3 tied together.

2.8 POWER BURN-IN CONDITIONS

Characteristics	Symbols	Test Conditions	Units
Case Temperature	T_{case}	+125 ±15, Note 1	°C
Junction Temperature	T_j	+150 (+0 -5)	°C
Average Output Rectified Current	I_O	≥ 10, Note 1	A

NOTES:
1. The case temperature and/or output current may be adjusted, within their given limit ranges, to attain the specified junction temperature.
2. For Variants 04, 05 testing shall be performed with both anode terminals 2 and 3 tied together.

2.9 OPERATING LIFE CONDITIONS

The conditions shall be as specified for Power Burn-in.

APPENDIX 'A'

AGREED DEVIATIONS FOR STMICROELECTRONICS (F)

ITEMS AFFECTED	DESCRIPTION OF DEVIATIONS
Deviations from Production Control - Chart F2	Special In-Process Controls - Internal Visual Inspection. Wedge bonds equal to 1.1 wire diameters are acceptable for bonding with a V-Groove tool.
Deviations from Screening Tests - Chart F3	Solderability is not applicable unless specifically stipulated in the Purchase Order.